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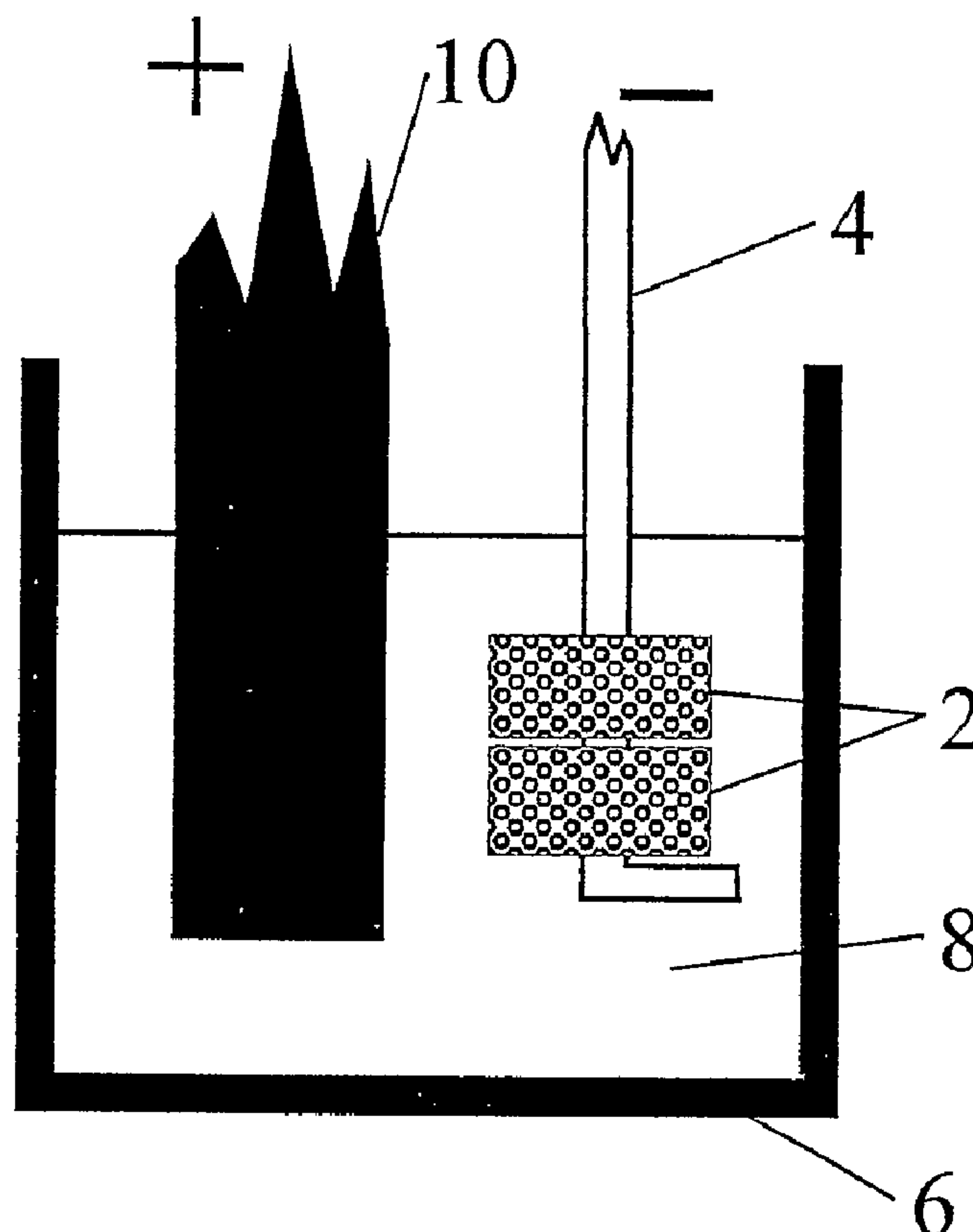
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(57) Abrégé/Abstract:

A method for the production of an intermetallic compound (M^1Z) involves treating a solid precursor material comprising three or more species, including first and second metal or metalloid species (M^1 , Z) and a non-metal species (X), by electro-deoxidation in contact with a melt comprising a fused salt (M^2Y) under conditions whereby the non-metal species dissolves in the melt. The first and second metal or metalloid species form an intermetallic compound. The method is performed in a cell comprising a cathode of the precursor material (2), which is immersed in a melt (8) contained in a crucible (6) for electro-deoxidation.

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INTERMETALLIC COMPOUNDS

Field of the Invention

This invention relates to a method and an apparatus
5 for preparing intermetallic compounds, and to
intermetallic compounds so produced.

Background to the Invention

Intermetallic compounds are compounds of a defined
structure comprising a metal and either a non-metal
10 (metalloid) or further metal. They have many
applications. For example silicon carbide is used in
metal matrix composites as a strengthening additive and
for furnace electrodes. Molybdenum silicide is also used
as a furnace element and as a strengthening agent.

15 Titanium diboride is used as a possible cathode material
for the Hall-Heroult cell for the extraction of alumina.

Carbides are amongst the most refractory materials
known. Many carbides have softening points above 3000°C
and the more refractory carbides possess some of the
20 highest melting points ever measured. Of the simple
carbides, the most refractory are HfC and TaC, which melt
at 3887°C and 3877°C. The complex carbides 4TaC.ZrC and
4TaC.HfC melt at 3932°C and 3942°C, respectively. Silicon
carbide is quite resistant to oxidation at temperatures up
25 to about 1500°C and has useful oxidation resistance for
many purposes at temperatures up to 1600°C. It is used
extensively for example as an abrasive, as a refractory
and as a resistor element for electric furnaces.

Most carbides have fair thermal and electrical
30 conductivity, and many of them are quite hard, boron
carbide being the hardest. High hardness accounts for the
usefulness of many of the carbides, such as silicon
carbide, titanium carbide, boron carbide and tungsten
carbide as materials for cutting, grinding and polishing
35 and for parts subject to severe abrasion or wear.

